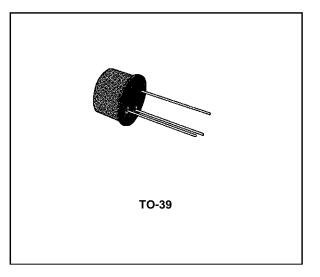


# BC140 BC141

## GENERAL PURPOSE TRANSISTORS

#### DESCRIPTION

The BC140 and BC141 are silicon planar epitaxial NPN transistors in TO-39 metal case. They are particularly designed for audio amplifiers and switching applications up to 1 A. The complementary PNP types are the BC160 and BC161.



#### INTERNAL SCHEMATIC DIAGRAM



#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Val		
	Farameter	BC140	BC141	Unit
V <sub>CBO</sub>	Collector-base Voltage $(I_E = 0)$	80	100	V
V <sub>CEO</sub>	Collector-emitter Voltage (I <sub>B</sub> = 0)	40 60		V
V <sub>EBO</sub>	Emitter-base Voltage (I <sub>C</sub> = 0)	7		V
Ic	Collector Current	1		А
Ι <sub>Β</sub>	Base Current	e Current 0.1		А
P <sub>tot</sub>	Total Power Dissipation at $T_{amb} \le 45 \ ^{\circ}C$	0.65		W
	at T <sub>case</sub> ≤ 45 °C	3.7		W
T <sub>stg</sub>	Storage Temperature	– 55 to 175		°C
Τj	Junction Temperature	175		°C

January 1989

#### THERMAL DATA

R <sub>th j-case</sub>	Thermal Resistance Junction-case	Max	35	°C/W
R <sub>th j-amb</sub>	Thermal Resistance Junction-ambient	Max	200	°C/W

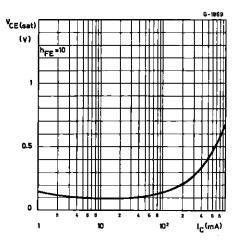
## **ELECTRICAL** CHARACTERISTICS ( $T_{amb} = 25 \ ^{\circ}C$ unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Unit	
I <sub>CES</sub>	Collector Cutoff Current $(I_E = 0)$	V <sub>CES</sub> = 60 V V <sub>CES</sub> = 60 V T <sub>amb</sub> = 150 °C			100 100	nA μA
V <sub>(BR)CBO</sub>	Collector-base Breakdown Voltage (I <sub>E</sub> = 0)	I <sub>C</sub> = 100 μA for <b>BC140</b> for <b>BC141</b>	80 100			V V
$V_{(BR)CEO}^{*}$	Collector-emitter Breakdown Voltage (I <sub>B</sub> = 0)	I <sub>C</sub> = 30 mA for <b>BC140</b> for <b>BC141</b>	40 60			V V
V <sub>(BR)EBO</sub>	Emitter-base Breakdown Voltage (I <sub>C</sub> = 0)	I <sub>E</sub> = 100 μA	7			V
V <sub>CE(sat)</sub> *	Collector-emitter Saturation Voltage			0.1 0.35 0.6	1	V V V
V <sub>BE</sub> *	Base-emitter Voltage	I <sub>C</sub> = 1 A V <sub>CE</sub> = 1 V		1.25	1.8	V
h <sub>FE</sub> *	DC Current Gain	$\begin{split} I_C &= 100 \; \mu A & V_{CE} &= 1 \; V \\ & for \; BC140-141 & for \; BC140-141 & for. 6 \\ & for \; BC140-141 & for. 10 \\ & for \; BC140-141 & for. 16 \\ I_C &= 100 \; mA & V_{CE} &= 1 \; V \\ & for \; BC140-141 & for. 6 \\ & for \; BC140-141 & for. 6 \\ & for \; BC140-141 & for. 16 \\ I_C &= 1 \; A & V_{CE} &= 1 \; V \\ & for \; BC140-141 & for. 6 \\ & for \; BC140-141 & for. 6 \\ & for \; BC140-141 & for. 6 \\ & for \; BC140-141 & for. 10 \\ & for \; BC140-141 & for. 10 \\ & for \; BC140-141 & for. 10 \\ & for \; BC140-141 & for. 16 \\ \end{split}$	40 40 63 100	75 28 40 90 140 63 100 160 26 15 20 30	250 100 160 250	
f⊤	Transition Frequency	$I_{C} = 50 \text{ mA}$ $V_{CE} = 10 \text{ V}$	50			MHz
C <sub>CBO</sub>	Collector-base Capacitance	I <sub>E</sub> = 0 V <sub>CB</sub> = 10 V f = 1 MHz		12	25	рF
t <sub>on</sub>	Turn-on Time	I <sub>C</sub> = 100 mA I <sub>B1</sub> = 5 mA			250	ns
t <sub>off</sub>	Turn-off Time	$I_{C} = 100 \text{ mA}$ $I_{B1} = I_{B2} = 5 \text{ mA}$			850	ns

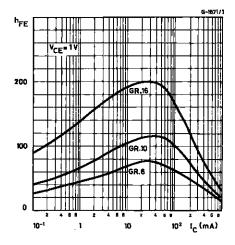
\* Pused : pulse duration =  $300 \,\mu$ s, duty cycle = 1 %.



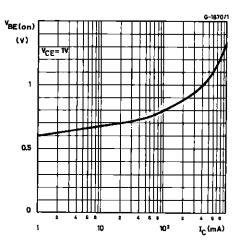
Collector-emitter Saturation Voltage.



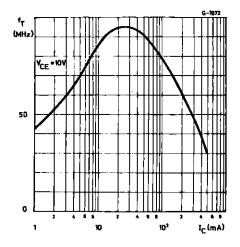
DC Curent Gain.



Base-emitter Voltage.



Transiition Frequency.

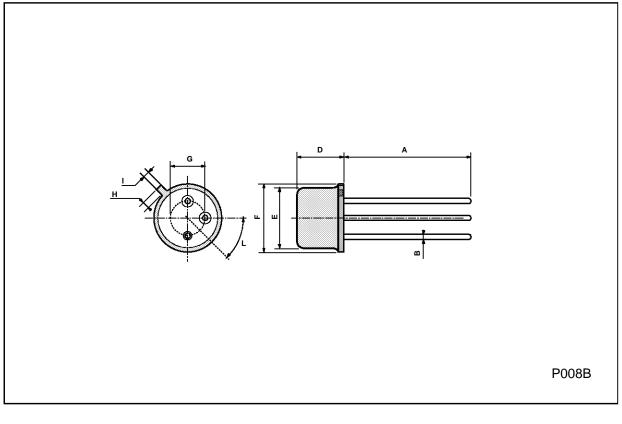




## BC140-BC141

## **TO39 MECHANICAL DATA**

DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А	12.7			0.500			
В			0.49			0.019	
D			6.6			0.260	
E			8.5			0.334	
F			9.4			0.370	
G	5.08			0.200			
н			1.2			0.047	
I			0.9			0.035	
L	45 <sup>°</sup> (typ.)						





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